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ON Semiconductor®

April 2017

# FNB80460T3

## Motion SPM® 8 Series

### Features

- UL Certified No. E209204 (UL1557)
- 600 V - 4 A 3-Phase IGBT Inverter Including Control IC for Gate Drive and Protections
- Low-Loss, Short-Circuit Rated IGBTs
- Separate Open-Emitter Pins from Low-Side IGBTs for Three-Phase Current Sensing
- Active-high interface, works with 3.3 / 5 V Logic, Schmitt-trigger Input
- HVIC for Gate Driving, Under-Voltage and Short-Circuit Current Protection
- Fault Output for Under-Voltage and Short-Circuit Current Protection
- Inter-Lock Function to Prevent Short-Circuit
- Shut-Down Input
- HVIC Temperature-Sensing Built-In for Temperature Monitoring
- Isolation Rating: 1500 V<sub>rms</sub> / min.

### Applications

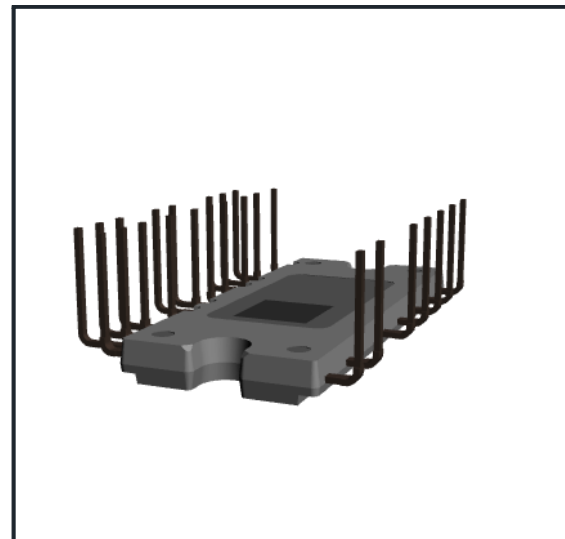
- Motion Control - Home Appliance / Industrial Motor

### Related Resources

- [AN-9112 - Smart Power Module, Motion SPM® 8 Series User's Guide.](#)
- [AN-9548 - SPM® 8 Package Assembly Guidance for 25L double DIP.](#)

### General Description

FNB80460T3 is a Motion SPM 8 module providing a fully-featured, high-performance inverter output stage for AC Induction, BLDC, and PMSM motors. These modules integrate optimized gate drive of the built-in IGBTs to minimize EMI and losses, while also providing multiple on-module protection features including under-voltage lockouts, inter-lock function, over-current shutdown, thermal monitoring of drive IC, and fault reporting. The built-in, high-speed HVIC requires only a single supply voltage and translates the incoming logic-level gate inputs to the high-voltage, high-current drive signals required to properly drive the module's robust short-circuit-rated IGBTs. Separate negative IGBT terminals are available for each phase to support the widest variety of control algorithms.



SPMFA-A25

Figure 1. 3D Package Drawing  
(Click to Activate 3D Content)

### Package Marking and Ordering Information

Device	Device Marking	Package	Packing Type	Quantity
FNB80460T3	NB80460T3	SPMFA-A25	RAIL	15

### Integrated Power Functions

- 600 V - 4 A IGBT inverter for three phase DC / AC power conversion (*Please refer to Figure 3*)

### Integrated Drive, Protection and System Control Functions

- For inverter high-side IGBTs: gate drive circuit, high-voltage isolated high-speed level shifting control circuit Under-Voltage Lock-Out (UVLO) protection  
 Note: Available bootstrap circuit example is given in Figures 5 and 17
- control circuit Under-Voltage Lock-Out (UVLO) protection
- For inverter low-side IGBTs: gate drive circuit, Over Current Protection(OCP), Short-Circuit Protection (SCP) control supply circuit Under-Voltage Lock-Out (UVLO) protection
- Fault signaling: corresponding to UVLO (low-side supply) and SC faults
- Input interface: High-active interface, works with 3.3 / 5 V logic, Schmitt trigger input

### Pin Configuration

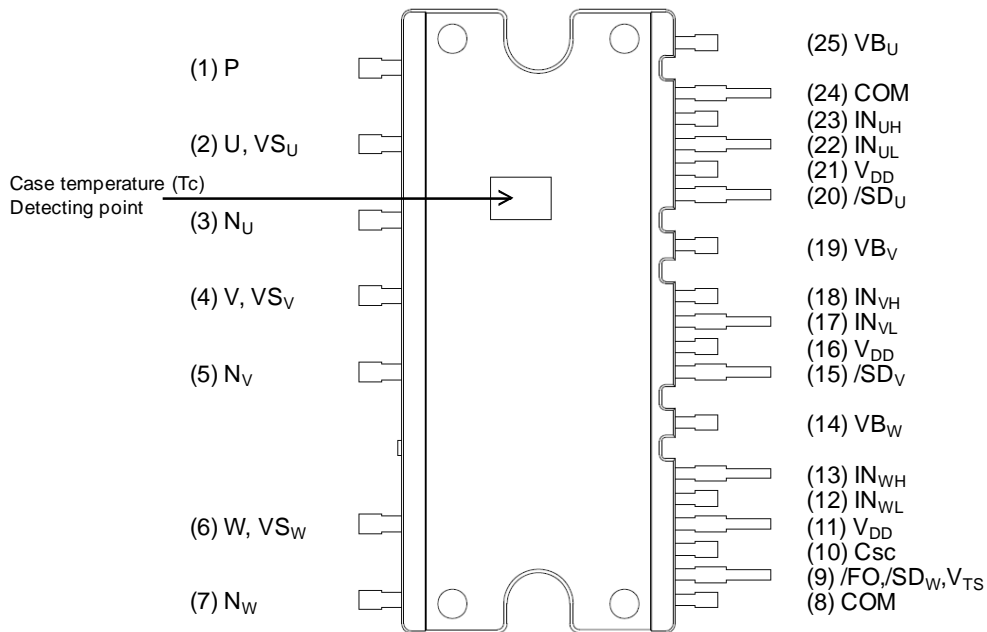
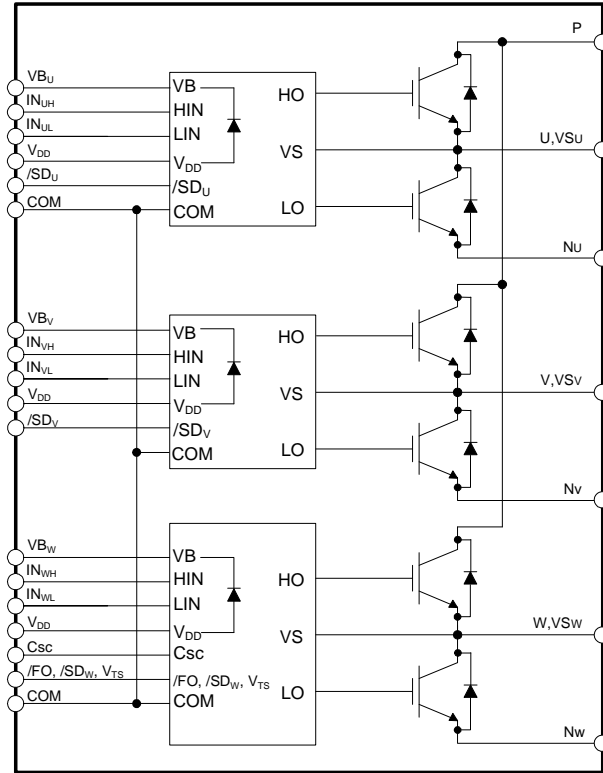


Figure 2. Top View

## Pin Descriptions

Pin Number	Pin Name	Pin Description
1	P	Positive DC-Link Input
2	U, VS <sub>U</sub>	Output for U Phase
3	N <sub>U</sub>	Negative DC-Link Input for U Phase
4	V, VS <sub>V</sub>	Output for V Phase
5	N <sub>V</sub>	Negative DC-Link Input for V Phase
6	W, VS <sub>W</sub>	Output for W Phase
7	N <sub>W</sub>	Negative DC-Link Input for W Phase
8	COM	Common Supply Ground
9	/FO, /SD <sub>W</sub> , V <sub>TS</sub>	Fault Output, Shut-Down Input for W Phase, Temperature Output of Drive IC
10	C <sub>SC</sub>	Shut Down Input for Over Current and Short Circuit Protection
11	V <sub>DD</sub>	Common Bias Voltage for IC and IGBTs Driving
12	IN <sub>WL</sub>	Signal Input for Low-Side W Phase
13	IN <sub>WH</sub>	Signal Input for High-Side W Phase
14	VB <sub>W</sub>	High-Side Bias Voltage for W-Phase IGBT Driving
15	/SD <sub>V</sub>	Shut-Down Input for V Phase
16	V <sub>DD</sub>	Common Bias Voltage for IC and IGBTs Driving
17	IN <sub>VL</sub>	Signal Input for Low-Side V Phase
18	IN <sub>VH</sub>	Signal Input for High-Side V Phase
19	VB <sub>V</sub>	High-Side Bias Voltage for V-Phase IGBT Driving
20	/SD <sub>U</sub>	Shut-Down Input for U Phase
21	V <sub>DD</sub>	Common Bias Voltage for IC and IGBTs Driving
22	IN <sub>UL</sub>	Signal Input for Low-Side U Phase
23	IN <sub>UH</sub>	Signal Input for High-Side U Phase
24	COM	Common Supply Ground
25	VB <sub>U</sub>	High-Side Bias Voltage for U-Phase IGBT Driving

### Internal Equivalent Circuit and Input/Output Pins



**Figure 3. Internal Block Diagram**

**Note:**

1. Inverter high-side is composed of three IGBTs, freewheeling diodes.
2. Inverter low-side is composed of three IGBTs, freewheeling diodes.
3. Inverter power side is composed of four inverter DC-link input terminals and three inverter output terminals.

## Absolute Maximum Ratings ( $T_J = 25^\circ\text{C}$ , unless otherwise specified.)

### Inverter Part

Symbol	Parameter	Conditions	Rating	Unit
$V_{PN}$	Supply Voltage	Applied between P - $N_U$ , $N_V$ , $N_W$	450	V
$V_{PN(\text{Surge})}$	Supply Voltage (Surge)	Applied between P - $N_U$ , $N_V$ , $N_W$	500	V
$V_{CES}$	Collector - Emitter Voltage		600	V
$\pm I_C$	Each IGBT Collector Current	$T_C = 25^\circ\text{C}$ , $T_J \leq 150^\circ\text{C}$ (Note 4)	4	A
$\pm I_{CP}$	Each IGBT Collector Current (Peak)	$T_C = 25^\circ\text{C}$ , $T_J \leq 150^\circ\text{C}$ , Under 1 ms Pulse Width (Note 4)	8	A
$T_J$	Operating Junction Temperature		-40 ~ 150	$^\circ\text{C}$

### Control Part

Symbol	Parameter	Conditions	Rating	Unit
$V_{DD}$	Control Supply Voltage	Applied between $V_{DD}$ - COM	20	V
$V_{BS}$	High-Side Control Bias Voltage	Applied between $V_{BU}$ - $V_{SU}$ , $V_{BV}$ - $V_{SV}$ , $V_{BW}$ - $V_{SW}$	20	V
$V_{IN}$	Input Signal Voltage	Applied between $IN_{UH}$ , $IN_{VH}$ , $IN_{WH}$ , $IN_{UL}$ , $IN_{VL}$ , $IN_{WL}$ - COM	-0.3 ~ $V_{DD} + 0.3$	V
$V_{FS}$	Function Supply Voltage	Applied between /FO, /SD <sub>W</sub> , $V_{TS}$ - COM	-0.3 ~ $V_{DD} + 0.3$	V
$I_{FO}$	Fault Current	Sink Current at /FO, /SD <sub>W</sub> , $V_{TS}$ pin	2	mA
$V_{SC}$	Current Sensing Input Voltage	Applied between $C_{SC}$ - COM	-0.3 ~ $V_{DD} + 0.3$	V

### Total System

Symbol	Parameter	Conditions	Rating	Unit
$V_{PN(\text{PROT})}$	Self Protection Supply Voltage Limit (Short Circuit Protection Capability)	$V_{DD} = V_{BS} = 13.5 \sim 16.5 \text{ V}$ , $T_J = 150^\circ\text{C}$ , Non-Repetitive, < 2 $\mu\text{s}$	400	V
$T_{STG}$	Storage Temperature		-40 ~ 125	$^\circ\text{C}$
$V_{ISO}$	Isolation Voltage Connect Pins to Heat Sink Plate	AC 60 Hz, Sinusoidal, 1 Minute, Connection Pins to Heat Sink Plate	1500	$V_{\text{rms}}$

### Thermal Resistance

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$R_{th(j-c)Q}$	Junction to Case Thermal Resistance (Note 5)	Inverter IGBT part, (Per Module)	-	-	3.65	$^\circ\text{C} / \text{W}$
$R_{th(j-c)F}$		Inverter FWDi part, (Per Module)	-	-	4.13	$^\circ\text{C} / \text{W}$

**Note:**

- These values had been made an acquisition by the calculation considered to design factor.
- For the measurement point of case temperature ( $T_C$ ), please refer to Figure 2.

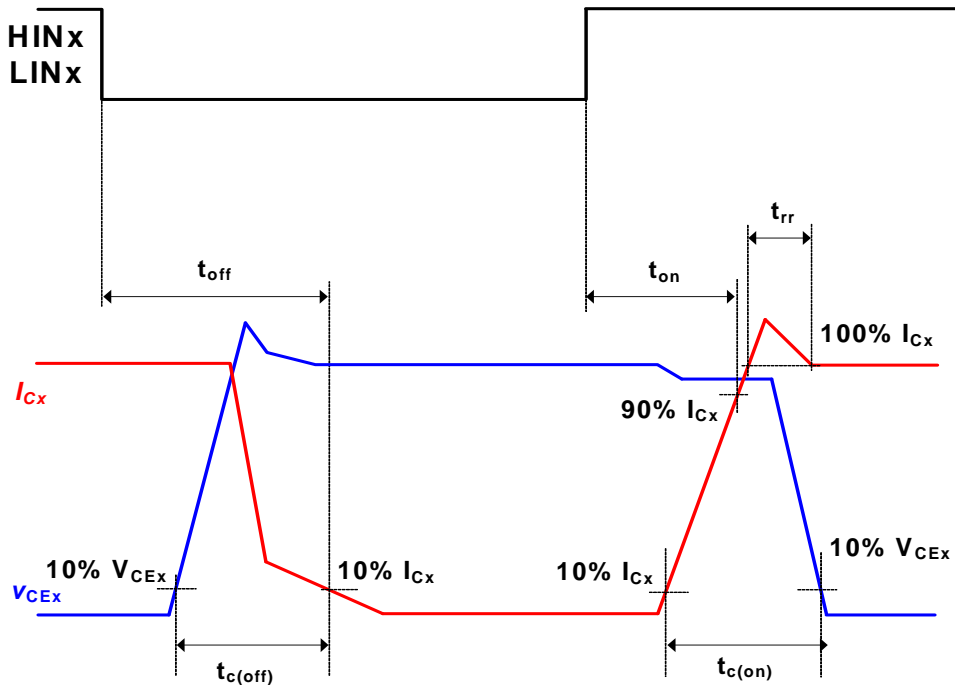
**Electrical Characteristics** ( $T_J = 25^\circ\text{C}$ , unless otherwise specified.)

**Inverter Part**

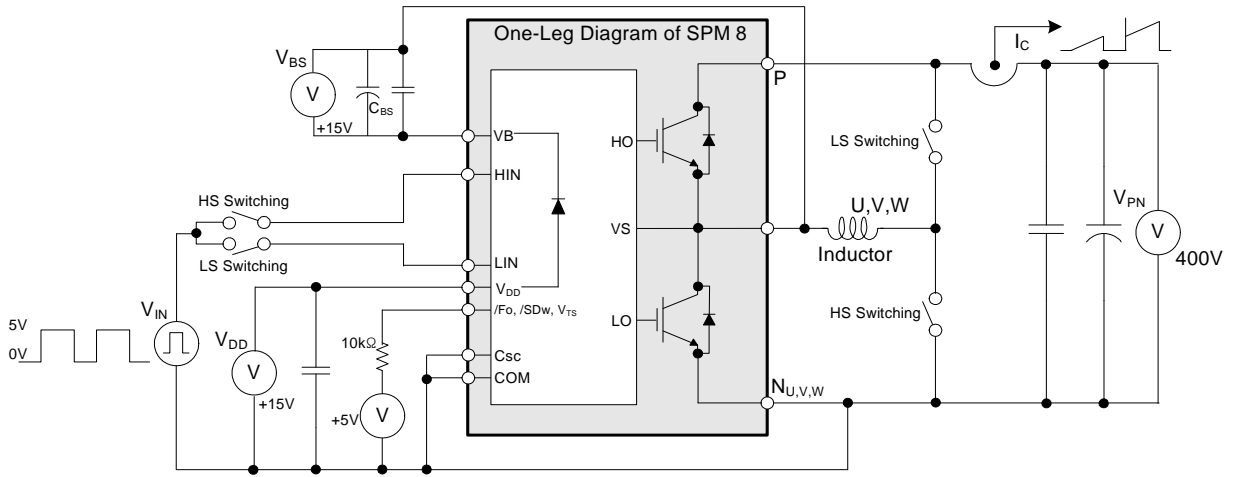
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit	
$V_{CE(SAT)}$	Collector - Emitter Saturation Voltage	$V_{DD} = V_{BS} = 15\text{ V}$ $V_{IN} = 5\text{ V}$ $I_C = 3\text{ A}$	$T_J = 25^\circ\text{C}$	-	1.85	2.30	V
			$T_J = 150^\circ\text{C}$	-	2.30	-	V
$V_F$	FWDi Forward Voltage	$V_{IN} = 0\text{ V}$ $I_F = 3\text{ A}$	$T_J = 25^\circ\text{C}$	-	1.95	2.50	V
			$T_J = 150^\circ\text{C}$	-	1.85	-	V
HS	$t_{ON}$	Switching Times $V_{PN} = 400\text{ V}, V_{DD} = V_{BS} = 15\text{ V}, I_C = 4\text{ A}$ $T_J = 25^\circ\text{C}$ $V_{IN} = 0\text{ V} \leftrightarrow 5\text{ V}$ , Inductive load (Note 6)		0.30	0.70	1.10	us
			$t_{C(ON)}$	-	0.15	0.45	us
			$t_{OFF}$	-	0.50	1.00	us
			$t_{C(OFF)}$	-	0.10	0.40	us
			$t_{rr}$	-	0.10	-	us
LS	$t_{ON}$	$V_{PN} = 400\text{ V}, V_{DD} = V_{BS} = 15\text{ V}, I_C = 4\text{ A}$ $T_J = 25^\circ\text{C}$ $V_{IN} = 0\text{ V} \leftrightarrow 5\text{ V}$ , Inductive load (Note 6)		0.30	0.70	1.10	us
			$t_{C(ON)}$	-	0.15	0.45	us
			$t_{OFF}$	-	0.50	1.00	us
			$t_{C(OFF)}$	-	0.10	0.40	us
			$t_{rr}$	-	0.10	-	us
$I_{CES}$	Collector - Emitter Leakage Current	$V_{CE} = V_{CES}$	-	-	1.00	mA	

**Note:**

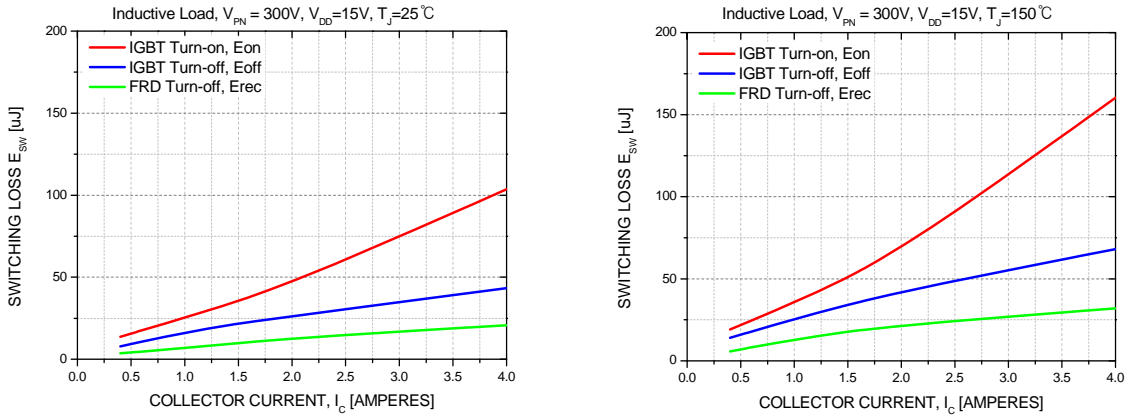
6.  $t_{ON}$  and  $t_{OFF}$  include the propagation delay of the internal drive IC.  $t_{C(ON)}$  and  $t_{C(OFF)}$  are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Figure 4.



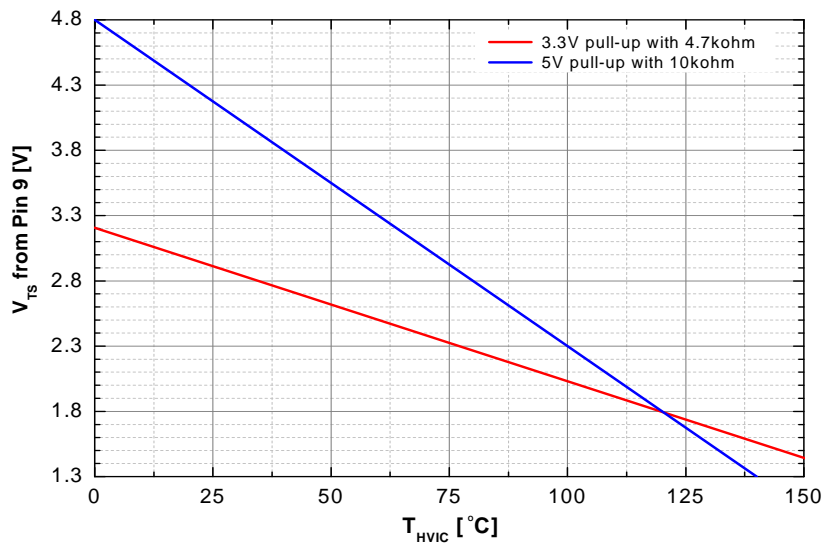
**Figure 4. Switching Time**



**Figure 5. Example Circuit for Switching Test**



**Figure 6. Switching Loss Characteristics**



**Figure 7. V-T Curve of Temperature Output of IC**



**Control Part**

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I <sub>QDD</sub>	Quiescent V <sub>DD</sub> Supply Current	V <sub>DD</sub> = 15 V, IN <sub>(UH,VH,WH,UL,VL,WL)</sub> = 0 V	V <sub>DD</sub> - COM	-	-	1.7 mA
I <sub>PDD</sub>	Operating V <sub>DD</sub> Supply Current	V <sub>DD</sub> = 15 V, f <sub>PWM</sub> = 20 kHz, duty = 50%, applied to one PWM signal input	V <sub>DD</sub> - COM	-	-	1.8 mA
I <sub>QBS</sub>	Quiescent V <sub>BS</sub> Supply Current	V <sub>BS</sub> = 15 V, IN <sub>(UH, VH, WH)</sub> = 0 V	V <sub>B(U)</sub> - V <sub>S(U)</sub> , V <sub>B(V)</sub> - V <sub>S(V)</sub> , V <sub>B(W)</sub> - V <sub>S(W)</sub>	-	-	100 μA
I <sub>PBS</sub>	Operating V <sub>BS</sub> Supply Current	V <sub>DD</sub> = V <sub>BS</sub> = 15 V, f <sub>PWM</sub> = 20 kHz, duty = 50%, applied to one PWM signal input for high - side	V <sub>B(U)</sub> - V <sub>S(U)</sub> , V <sub>B(V)</sub> - V <sub>S(V)</sub> , V <sub>B(W)</sub> - V <sub>S(W)</sub>	-	-	300 μA
V <sub>FOH</sub>	Fault Output Voltage	V <sub>SC</sub> = 0 V, V <sub>F</sub> Circuit: 10 kΩ to 5 V Pull-up	3.81	-	-	V
V <sub>FOL</sub>		V <sub>SC</sub> = 1 V, V <sub>F</sub> Circuit: 10 kΩ to 5 V Pull-up	-	-	0.5	V
V <sub>SC(ref)</sub>	Short-Circuit Trip Level	V <sub>DD</sub> = 15 V (Note 7)	0.46	0.49	0.52	V
UV <sub>DDD</sub>	Supply Circuit Under-Voltage Protection	Detection level	10.0	11.5	13.0	V
UV <sub>DDR</sub>		Reset level	10.5	12.0	13.5	V
UV <sub>BSD</sub>		Detection level	9.5	11.0	12.5	V
UV <sub>BSR</sub>		Reset level	10.0	11.5	13.0	V
I <sub>FO_T</sub>	HVIC Temperature Sensing Current	V <sub>DD</sub> = V <sub>BS</sub> = 15 V, T <sub>HVIC</sub> = 25°C	-	82.5	-	μA
		V <sub>DD</sub> = V <sub>BS</sub> = 15 V, T <sub>HVIC</sub> = 75°C	-	207.5	-	μA
V <sub>FO_T</sub>	HVIC Temperature Sensing Voltage See Figure 7	V <sub>DD</sub> = V <sub>BS</sub> = 15 V, T <sub>HVIC</sub> = 25°C, 10 kΩ to 5 V Pull-up	-	4.18	-	V
		V <sub>DD</sub> = V <sub>BS</sub> = 15 V, T <sub>HVIC</sub> = 75°C, 10 kΩ to 5 V Pull-up	-	2.93	-	V
t <sub>FOD</sub>	Fault-Out Pulse Width		40	-	-	μs
V <sub>FSDR</sub>	Shut-down Reset level	Applied between /FO - COM	-	-	2.4	V
V <sub>FSDD</sub>	Shut-down Detection level		0.8	-	-	V
V <sub>IN(ON)</sub>	ON Threshold Voltage	Applied between IN <sub>(UH)</sub> , IN <sub>(VH)</sub> , IN <sub>(WH)</sub> , IN <sub>(UL)</sub> , IN <sub>(VL)</sub> , IN <sub>(WL)</sub> - COM	-	-	2.4	V
V <sub>IN(OFF)</sub>	OFF Threshold Voltage		0.8	-	-	V

**Note:**

7. Short-circuit current protection function is for all six IGBTs if the /FO, /SD<sub>W</sub>, V<sub>TS</sub> pin is connected to /SD<sub>x</sub> pins.

### Bootstrap Diode Part

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
R <sub>BS</sub>	Bootstrap Diode Resitance	V <sub>DD</sub> = 15V, T <sub>J</sub> = 25°C	-	280	-	Ω

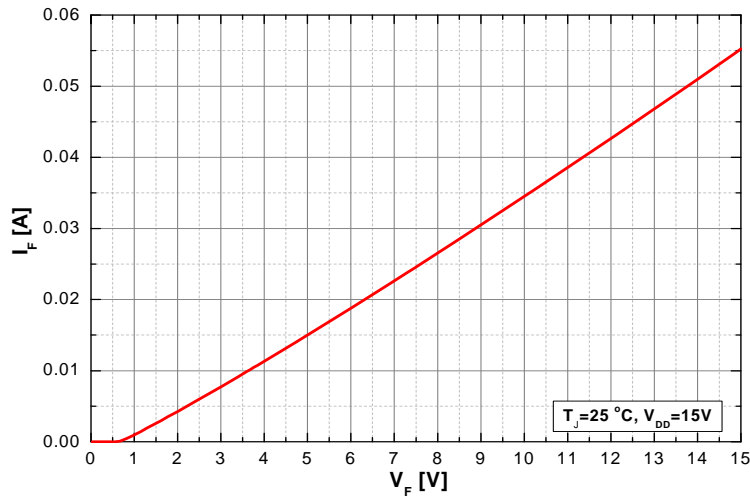


Figure 8. Built-In Bootstrap Diode Charaterstics

### Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V <sub>PN</sub>	Supply Voltage	Applied between P - N <sub>U</sub> , N <sub>V</sub> , N <sub>W</sub>	-	300	400	V
V <sub>DD</sub>	Control Supply Voltage	Applied between V <sub>DD</sub> - COM	14.0	15	16.5	V
V <sub>BS</sub>	High - Side Bias Voltage	Applied between V <sub>B<sub>U</sub></sub> - V <sub>S<sub>U</sub></sub> , V <sub>B<sub>V</sub></sub> - V <sub>S<sub>V</sub></sub> , V <sub>B<sub>W</sub></sub> - V <sub>S<sub>W</sub></sub>	13.0	15	18.5	V
dV <sub>DD</sub> / dt, dV <sub>BS</sub> / dt	Control Supply Variation		-1	-	1	V / μs
t <sub>dead</sub>	Blanking Time for Preventing Arm - Short	For each input signal	0.5	-	-	μs
V <sub>SEN</sub>	Voltage for Current Sensing	Applied between N <sub>U</sub> , N <sub>V</sub> , N <sub>W</sub> - COM (Including surge voltage)	-4		4	V
P <sub>WIN(ON)</sub>	Minimum Input Pulse Width	V <sub>DD</sub> = V <sub>BS</sub> = 15 V, I <sub>C</sub> ≤ 10 A, Wiring Inductance between N <sub>U</sub> , v, w and DC Link N < 10nH (Note 8)	0.7	-	-	μs
P <sub>WIN(OFF)</sub>			0.7	-	-	

**Note:**

8. This product might not make response if input pulse width is less than the recommended value.

## Mechanical Characteristics and Ratings

Parameter	Conditions	Min.	Typ.	Max.	Unit	
Device Flatness	See Figure 9	-50	-	100	μm	
Mounting Torque	Mounting Screw: - M3 See Figure 10	Recommended 0.7 N • m	0.6	0.7	0.8	N • m
		Recommended 7.1 kg • cm	5.9	6.9	7.9	kg • cm
Weight		-	5.0	-	g	

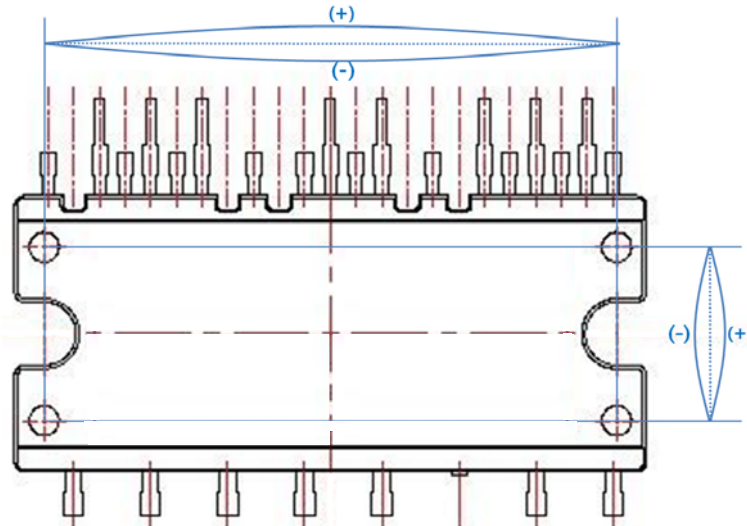


Figure 9. Flatness Measurement Position

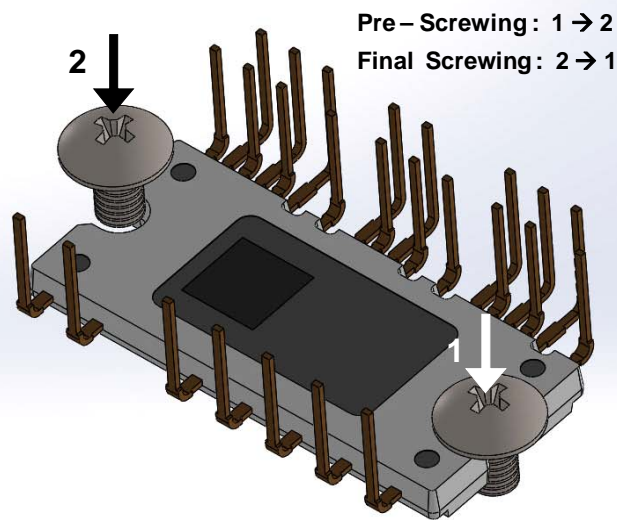


Figure 10. Mounting Screws Torque Order

**Note:**

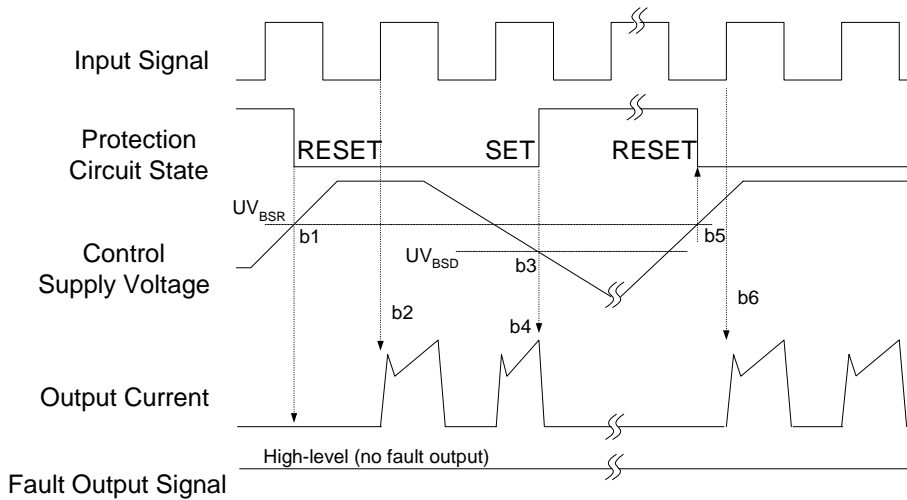
- 9. Do not make over torque when mounting screws. Much mounting torque may cause package cracks, as well as bolts and Al heat-sink destruction.
- 10. Avoid one side tightening stress. Figure 10 shows the recommended torque order for mounting screws. Uneven mounting can cause of package to be damaged.  
The pre-screwing torque is set to 20 ~ 30 % of maximum torque rating.

## Time Charts of Protective Function



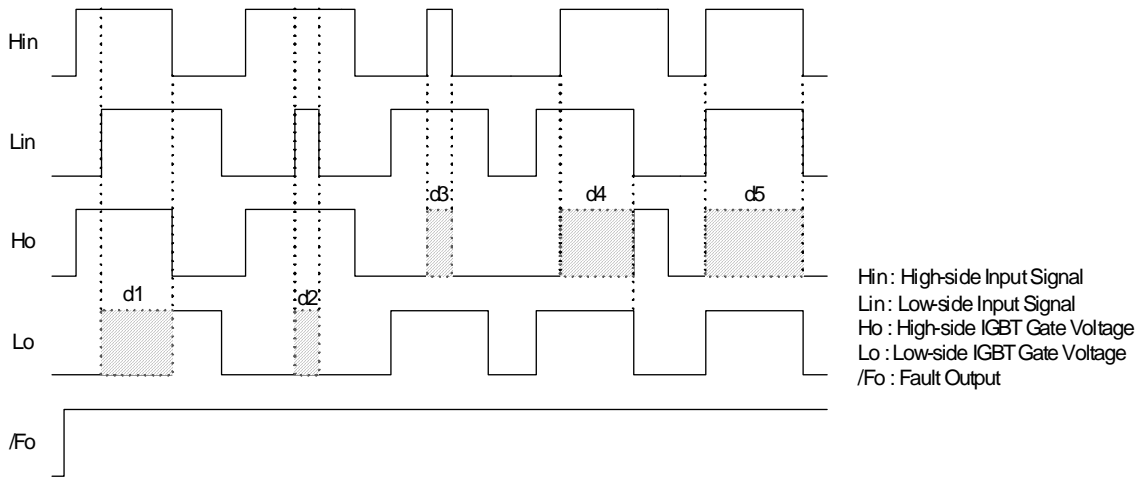
**Figure 11. Under-Voltage Protection (Low-Side)**

- a1 : Control supply voltage rises: After the voltage rises  $UV_{DDR}$ , the circuits start to operate when next input is applied.
- a2 : Normal operation: IGBT ON and carrying current.
- a3 : Under voltage detection ( $UV_{DD}$ ).
- a4 : IGBT OFF in spite of control input condition.
- a5 : Fault output operation starts.
- a6 : Under voltage reset ( $UV_{DDR}$ ).
- a7 : Normal operation: IGBT ON and carrying current.



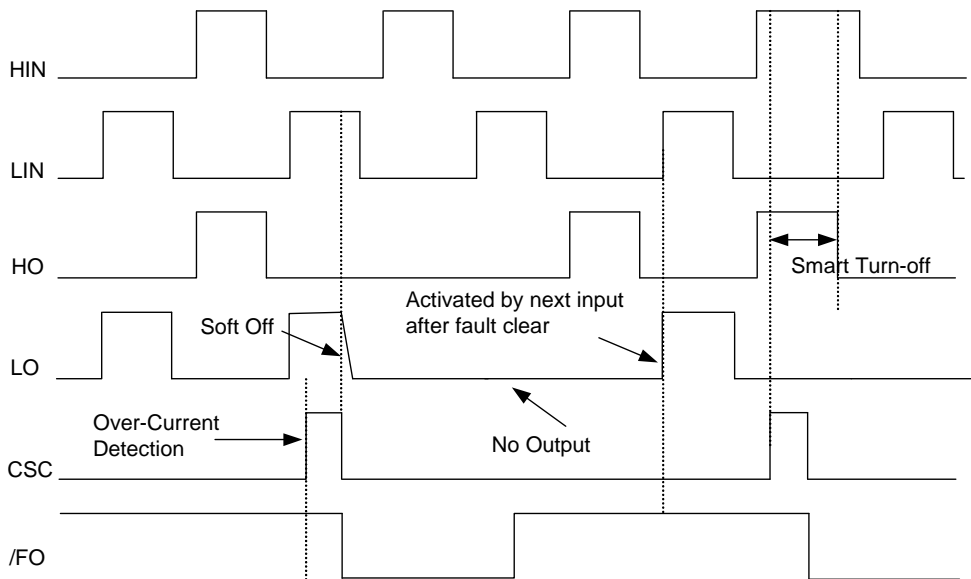
**Figure 12. Under-Voltage Protection (High-Side)**

- b1 : Control supply voltage rises: After the voltage reaches  $UV_{BSR}$ , the circuits start to operate when next input is applied.
- b2 : Normal operation: IGBT ON and carrying current.
- b3 : Under voltage detection ( $UV_{BSD}$ ).
- b4 : IGBT OFF in spite of control input condition, but there is no fault output signal.
- b5 : Under voltage reset ( $UV_{BSR}$ )
- b6 : Normal operation: IGBT ON and carrying current



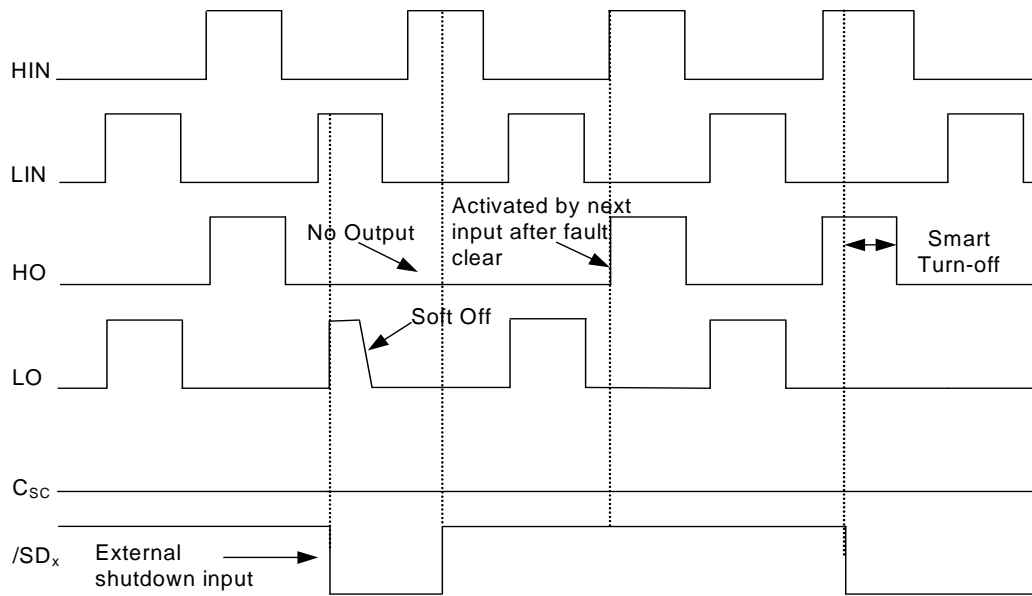
**Figure 13. Inter-Lock Function**

- d1 : High Side First - Input - First - Output Mode
- d2 : Low Side Noise Mode : No LO
- d3 : High Side Noise Mode : No HO
- d4 : Low Side First - Input - First - Output Mode
- d5 : IN - Phase Mode : No HO



**Figure 14. Fault-Out Function By Over Current Protection**

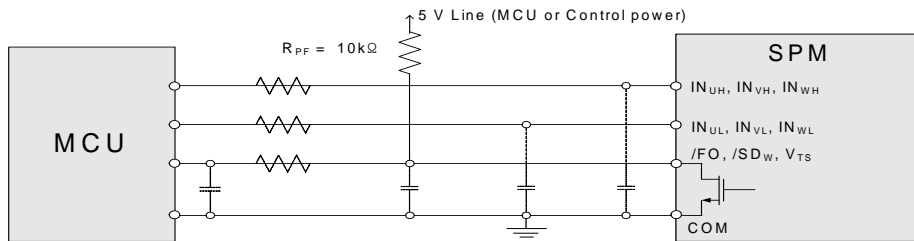
- HIN : High-side Input Signal
- LIN : Low-side Input Signal
- HO : High-Side Output Signal
- LO : Low-Side Output Signal
- CSC : Over Current Detection Input
- /FO : Fault Out Function



**Figure 15. Shutdown Input Function By External Command**

HIN : High-side Input Signal  
 LIN : Low-side Input Signal  
 HO : High-Side Output Signal  
 LO : Low-Side Output Signal  
 C<sub>sc</sub> : Over Current Detection Input  
 /SD<sub>x</sub> : Shutdown Input Function

**Input/Output Interface Circuit**

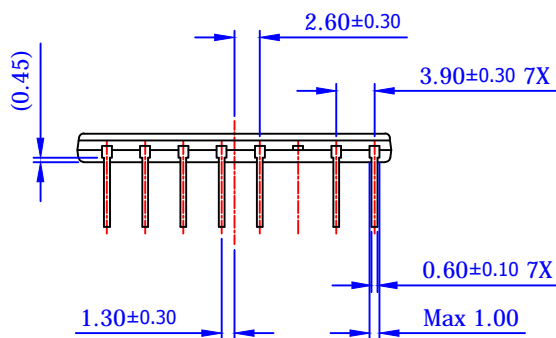
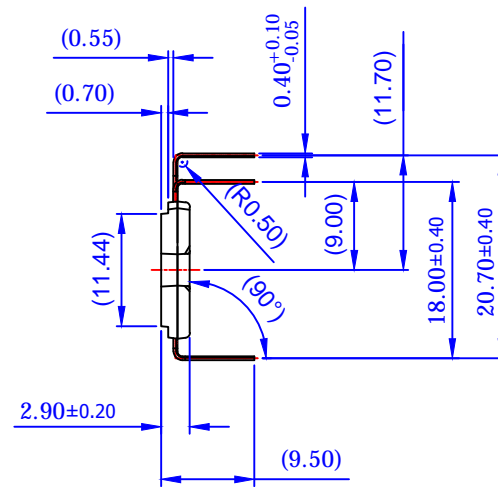
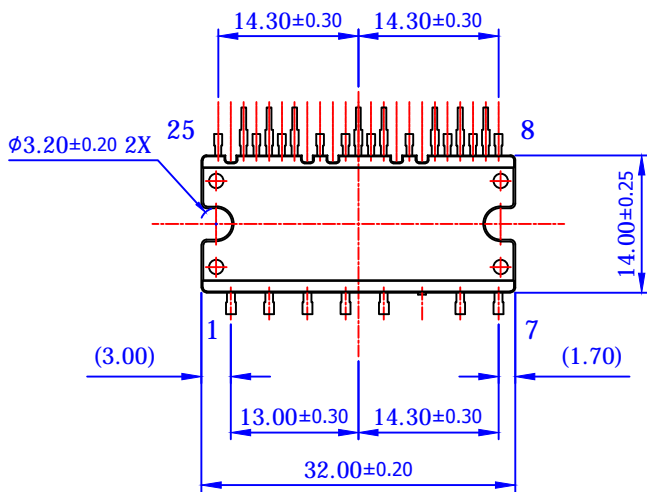
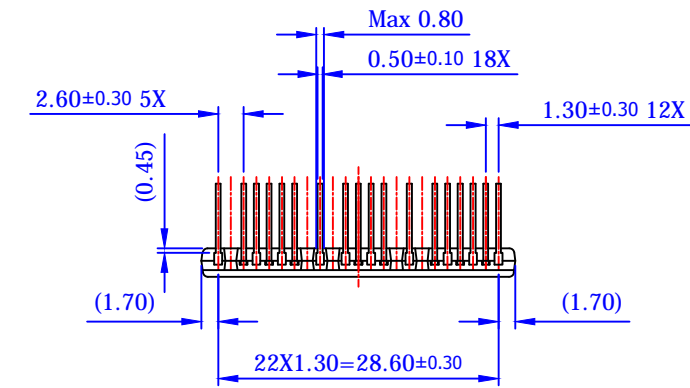


**Figure 16. Recommended MCU I/O Interface Circuit**

**Note:**

11. RC coupling at each input (parts shown dotted) might change depending on the PWM control scheme used in the application and the wiring impedance of the application's printed circuit board. The input signal section of the SPM 8 product integrates 5 kΩ (typ.) pull-down resistor. Therefore, when using an external filtering resistor, please pay attention to the signal voltage drop at input terminal.





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